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√1. A direct current sum bandgap voltage comparator comprising:

a summing node;

a plurality of current sources connected to the summing node, each current source further comprising at least one transistor, and each current source supplying a current to the summing node and being connected to a power supply voltage, wherein the currents sources supply currents according to a bandgap equation:

$$K_1(V_{CC}-V_T)+K_1V_T=K_2V_{BE}+K_3(kT/q)$$

where V_{CC} is the power supply voltage, V_T is a predetermined threshold voltage of a transistor in a first current source within the plurality of current sources, V_{BE} is a base emitter voltage of a transistor in a second current source within the plurality of current sources, k is Boltzman's constant, T is a temperature in kelvin of a transistor in a third current source within the plurality of current sources, q is an electronic charge constant, and K_1 , K_2 , and K_3 are constants

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determined by a resistance and a transistor length in the first, second, and third current sources, respectively; and

an indicator circuit having an input connected to the summing node and generating a logical signal at an output, responsive to voltage changes in the summing node.

2. The direct current sum bandgap voltage comparator of claim 1, wherein the plurality of current sources are current mirrors.

✓3. A direct current sum bandgap voltage comparator comprising:

a summing node;

a plurality of current sources connected to the summing node, each current source further comprising at least one transistor, and each current source supplying a current to the summing node and being connected to a power supply voltage; and

an indicator circuit having an input connected to the summing node and generating a logical signal at an output, responsive to voltage changes in the summing node, wherein the currents sources supply currents according to a bandgap equation:

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$$K_1(V_{CC}-V_T)+K_1V_T=K_2V_{BE}+K_3(kT/q)$$

where V_{CC} is the power supply voltage, V_T is a predetermined threshold voltage of a transistor in a first current source within the plurality of current sources, V_{BE} is a base emitter voltage of a transistor in a second current source within the plurality of current sources, k is Boltzman's constant, T is a temperature in kelvin of a transistor in a third current source within the plurality of current sources, q is an electronic charge constant, and K_1 , K_2 , and K_3 are constants determined by a resistance and a transistor length in the first, second, and third current sources, respectively, and wherein the plurality of current sources comprises four current mirrors.

4. The direct current sum bandgap voltage comparator of claim 3, wherein the first current mirror includes a plurality of transistors and supplies a current to the summing node defined by $K_1(V_{CC}-V_T)$.

5. The direct current sum bandgap voltage comparator of claim 4, wherein the second current mirror includes a plurality of transistors and supplies a current to the summing node defined by K_1V_T .

6. The direct current sum bandgap voltage comparator of claim 5, wherein the third current mirror includes a plurality of transistors and supplies a current to the summing node defined by K_2V_{BE} .

7. The direct current sum bandgap voltage comparator of claim 6, wherein the fourth current mirror supplies a current to the summing node defined by $K_3(kT/q)$.

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8. The direct current sum bandgap voltage comparator of claim 7 further comprising a clamping circuit connected to the summing node, wherein a voltage swing for the summing node, responsive to changes in current supplied by the current mirrors, may be set between predetermined voltages.

9. The direct current sum bandgap voltage comparator of claim 7 further comprising a cascode stage having at least a first and second connections, the first connection is connected to the summing node and the second connection is connected to one of the four current mirrors.

10. The direct current sum bandgap voltage comparator of claim 7 further comprising a hysteresis circuit connected to the indicator circuit to reduce noise.

11. The direct current sum bandgap voltage comparator of claim 7, wherein the indicator circuit includes a pair of

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inverters connected in series, wherein an input in the first inverter is the input of the indicator circuit connected to the summing node and an output of the second inverter is the output of the indicator circuit.

12. The direct current sum bandgap voltage comparator of claim 11, wherein the indicator circuit provides a logic one output if the power supply is equal to or greater than a preselected voltage.

✓ 13. A zero power circuit comprising:

a first circuit;

a direct current sum bandgap voltage comparator comprising:

a summing node;

a plurality of current sources connected to the summing node, each current source further comprising at least one transistor, and each current source supplying a current to the summing node and being connected to a power supply voltage, wherein the current sources supply according to a bandgap equation:

$$K_1(V_{CC}-V_T)+K_1V_T=K_2V_{BE}+K_3(kT/q)$$

where V_{CC} is the power supply voltage, V_T is a predetermined threshold voltage of a transistor in a first current source within the plurality of current sources, V_{BE} is a base emitter voltage of a transistor in a second current source within the plurality of current sources, k is Boltzman's constant, T is a temperature in kelvin of a transistor in a third current source within the plurality of current sources, q is an electronic charge constant, and K_1 , K_2 , and K_3 are constants determined by a resistance and a transistor length in the first, second, and third current sources, respectively;

an indicator circuit having an input connected to the summing node and generating a logical signal at an

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**output, responsive to changes in the summing node;
and**

a switching circuit for providing power to the first circuit from a primary power supply and a secondary power supply, the switching circuit being connected to the output of the indicator circuit, wherein power from the primary power supply is supplied to the first circuit if the logical signal indicates that the power supply voltage is equal to or greater than the predetermined threshold voltage and power from the secondary power supply is supplied to the first circuit if the power supply voltage is less than the predetermined threshold voltage.

✓ 14. A zero power circuit comprising:

a first circuit;

a direct current sum bandgap voltage comparator comprising:

a summing node;

a plurality of current sources connected to the summing node, each current source further comprising at least one transistor, and each current source supplying a current to the summing node and being connected to a power supply voltage;

**an indicator circuit having an input connected to the summing node and generating a logical signal at an output, responsive to changes in the summing node;
and**

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a switching circuit for providing power to the first circuit from a primary power supply and a secondary power supply, the switching circuit being connected to the output of the indicator circuit, wherein power from the primary power supply is supplied to the first circuit if the logical signal indicates that the power supply voltage is equal to or greater than the preselected voltage and power from the secondary power supply is supplied to the first circuit if the power supply voltage is less than the preselected voltage, wherein the current sources supply according to a bandgap equation:

$$K_1(V_{CC}-V_T)+K_1V_T=K_2V_{BE}+K_3(kT/q)$$

where V_{CC} is the power supply voltage, V_T is a predetermined threshold voltage of a transistor in a first current source within the plurality of current sources, V_{BE} is a base emitter voltage of a transistor in a second current source within the plurality of current sources, k is Boltzman's constant, T is a temperature in kelvin of a transistor in a third current source within the plurality of current sources, q is an electronic charge constant, and K_1 , K_2 , and K_3 are constants determined by a resistance and a transistor length in the first, second, and third current sources, respectively, and wherein the plurality of current sources comprises four current mirrors.

15. The zero power circuit of claim 14, wherein the secondary power supply is a battery.

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16. The zero power circuit of claim 14, wherein the first current mirror includes a plurality of transistors and supplies a current to the summing node defined by $K_1(V_{CC}-V_T)$.

17. The zero power circuit of claim 14, wherein the second current mirror includes a plurality of transistors and supplies a current to the summing node defined by $K_1 V_T$.

18. The zero power circuit of claim 17, wherein the third current mirror includes a plurality of transistors and supplies a current to the summing node defined by $K_2 V_{BE}$.

19. The zero power circuit of claim 18, wherein the fourth current mirror supplies a current to the summing node defined by $K_3(kT/q)$.

20. The zero power circuit of claim 19 further comprising a clamping circuit connected to the summing node, wherein a voltage swing for the summing node, responsive to changes in current supplied by the current mirrors, may be set between selected voltages.

21. The zero power circuit of claim 19 further comprising a cascode stage located between the summing node and the current mirrors.

22. The zero power circuit of claim 19 further comprising a hysteresis circuit connected to the indicator circuit to reduce noise.

23. The direct current sum bandgap voltage comparator of claim 19, wherein the indicator circuit provides a logic one output if the power supply is equal to or greater than a preselected voltage.

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24-27. (Cancelled).

28. A method, comprising:
generating a first current that changes with temperature according to a first
polarity;
generating a second current that changes with temperature according to a
second polarity;
combining the first and second currents to generate a reference current; and
comparing the reference current to a third current that is dependent on a
power-supply voltage.

29. The method of claim 28 wherein:
the first current changes with temperature according to a positive polarity; and
the second current changes with temperature according to a negative polarity.

30. The method of claim 28 wherein:
the first current is proportional to temperature; and
the second current is inversely proportional to temperature

31. The method of claim 28 wherein:
the first current increases as temperature increases and decreases as
temperature decreases; and
the second current decreases as temperature increases and increases as
temperature decreases.

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32. The method of claim 28 wherein combining the first and second currents comprises summing the first and second currents.

33. The method of claim 28 wherein combining the first and second currents comprises sinking the first and second currents from a node.

34. The method of claim 28 wherein combining the first and second currents comprises sourcing the first and second currents to a node.

35-39. (Cancelled)

40. A method, comprising:
generating a first current that increases as temperature increases and that decreases as temperature decreases;
generating a second current that decreases as temperature increases and that increases as temperature decreases;
generating a third current that is dependent on a first voltage; and
combining the first, second, and third currents at a node to generate a second voltage on the node.

41. The method of claim 40 wherein combining the currents comprises:
sinking the first and second currents from the node; and
sourcing the third current to the node.

42. The method of claim 40 wherein:
the first current is related to a thermal voltage; and
the second current is related to a voltage across a forward-biased p-n junction.

43. The method of claim 40 wherein:
the first current is related to a thermal voltage; and
the second current is related to a base-emitter voltage of a bipolar transistor.

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44. The method of claim 40 wherein the second current is related to the natural logarithm of a current through a bipolar transistor.

45. A method, comprising:
generating a first current that is related to temperature according to a first polarity;
generating a second current that is related to temperature according to a second polarity;
combining the first and second currents into a reference current;
generating a third current that is dependent on a first voltage; and
comparing the third current to the reference current.

46. The method of claim 45 wherein:
the first current is related to a thermal voltage;
the second current is related to a voltage across a forward-biased p-n junction;
and
the third current is dependent on a power-supply voltage.

47. The method of claim 45 wherein:
combining the first and second currents comprises sinking the first and second currents from a node; and
comparing the third current to the reference current comprises,
sourcing the third current to the node, and
comparing a second voltage on the node to a reference voltage.

48. A method, comprising:
generating a first current that is proportional to a threshold voltage of a field-effect transistor;
generating a second current that is proportional to a difference between a supply voltage and a threshold voltage of a second field-effect transistor;
generating a third current that is proportional to a base-emitter voltage of a first bipolar transistor;

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generating a fourth current that is proportional to absolute temperature; and
driving a node with the first, second, third, and fourth currents.

49. The method of claim 48 wherein driving the node comprises:
sourcing the first and second currents to the node; and
sinking the third and fourth currents from the node.

50. The method of claim 48, further comprising comparing a voltage on the
node with a reference voltage.

51. The method of claim 48 wherein the first field-effect transistor is matched
to the second field-effect transistor.

52. The method of claim 48 wherein the threshold voltage of the first
field-effect transistor is equal or approximately equal to the threshold voltage of the
second field-effect transistor.

53. A method, comprising:
generating a first current that equals a product of a first constant and a threshold
voltage of a first field-effect transistor;
generating a second current that equals a product of a second constant and a
difference between a supply voltage and a threshold voltage of a second field-effect
transistor;
generating a third current that equals a product of a third constant and a
base-emitter voltage of a bipolar transistor;
generating a fourth current that equals a product of a fourth constant and a
thermal voltage; and
driving a node with the first, second, third, and fourth currents.

54. The method of claim 53 wherein the first constant equals the second
constant.

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55. The method of claim 53 wherein driving the node comprises:
sourcing the first and second currents to the node; and
sinking the third and fourth currents from the node.

56. A method, comprising:
generating a first current that changes with temperature according to a first
polarity;
generating a second current that changes with temperature according to a
second polarity;
combining the first and second currents to generate a reference current; and
comparing the reference current to a third current that is proportional to a
power-supply voltage.

57. The method of claim 28 wherein comparing the reference current
comprises summing the reference current and the third current at a node.

58. The method of claim 28 wherein comparing the reference current
comprises:
sinking the reference current from a node; and
sourcing the third current to the node.

59. A method, comprising:
generating with a first current source that is powered by a supply voltage a
reference current that has a temperature coefficient and that is independent of the
supply voltage;
providing the reference current at a node;
generating with a second current source that is powered by the supply voltage a
supply-related current having approximately the temperature coefficient and being
related to the supply voltage;
providing the supply-related current at the node; and
comparing the reference current to the supply-related current at the node.

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60. The method of claim 59 wherein:
providing the reference current at the node comprises sinking the reference
current from the node; and
providing the supply-related current at the node comprises sourcing the
supply-related current to the node.

61. The method of claim 59 wherein comparing the reference current
comprises summing the reference current and the supply-related current at the node to
generate a voltage.

62. A method, comprising:
generating a reference current having a first temperature coefficient;
comparing the reference current to a supply-related current that is related to a
power-supply voltage and that has or has approximately the first temperature
coefficient;
wherein comparing the reference current comprises summing the reference
current and the supply-related current at a node to generate a voltage;
connecting the power-supply voltage to a load if the voltage is greater than a
predetermined level; and
connecting a secondary supply to the load if the voltage is less than the
predetermined level.

63. A method, comprising:
generating a first current that is related to temperature according to a first
polarity;
generating a second current that is related to temperature according to a second
polarity;
combining the first and second currents into a reference current;
generating a third current that is related to temperature according to the first
polarity;
generating a fourth current that is related to a supply voltage and that is related
to temperature according to the second polarity;

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combining the third and fourth currents into a supply-related current; and
comparing the reference current to the supply-related current.

64. The method of claim 63 wherein the fourth current is proportional to the
supply voltage.

65. The method of claim 63 wherein the supply-related current is proportional
to the supply voltage.

66. The method of claim 63 wherein:
the first and third currents are inversely proportional to temperature; and
the second and fourth currents are proportional to temperature.

CLAIM 67 (CANCELLED)

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68. A method, comprising:

generating with a first current source that is powered by a supply voltage a reference current that has a temperature coefficient and that is independent of the supply voltage;

providing the reference current at a node;

generating with a second current source that is powered by the supply voltage a supply-related current having approximately the temperature coefficient and being related to the supply voltage;

providing the supply-related current at the node; and

neither sourcing to nor sinking from the node a current other than the reference and supply-related currents.

69. A method comprising:

generating with a first current source that is powered by a supply voltage a reference current that has a temperature coefficient and that is independent of the supply voltage;

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providing the reference current at a comparison node;

generating with a second current source that is powered by the supply voltage a supply-related current having approximately the temperature coefficient and being related to the supply voltage;

providing the supply-related current at the comparison node; and

comparing a voltage on the comparison node to a reference voltage.

70. The method of claim 68 wherein:

providing the reference current at the node comprises sinking the reference current from the node; and

providing the supply-related current at the node comprises sourcing the supply-related current to the node.

71. The method of claim 69 wherein:

providing the reference current at the comparison node comprises sinking the reference current from the comparison node; and

providing the supply-related current at the comparison node comprises sourcing the supply-related current to the comparison node.